



MMDT5401

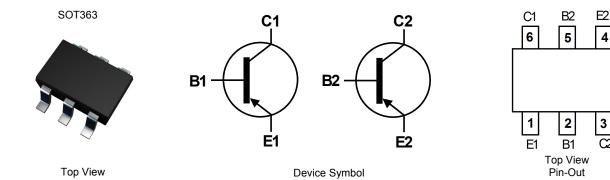
150V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMDT5551)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound,
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)



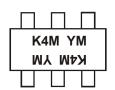
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDT5401-7-F	K4M	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



K4M = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

	.,				_				_			
Year	2009	20	10	2011	2012	20	13	2014	2015	20	16	2017
Code	W	>	<	Y	Z		4	В	С)	Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	Ic	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	200	mW	
Power Dissipation	(Notes 6 & 7)	P _D	320	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 5)	625			
Thermal Resistance, Junction to Ambient	(Notes 6 & 7)	$R_{ hetaJA}$	390	°C/W	
Thermal Resistance, Junction to Case (Note 8)		R ₀ JC	140		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

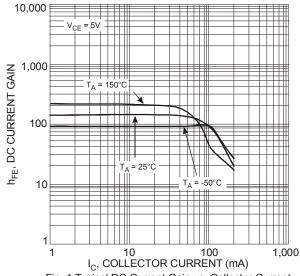
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS								
Collector-Base Breakdown Voltage		-160	_	_	V	$I_C = -100\mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-150	_	_	V	$I_C = -1 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	BV_{EBO}	-6	_	_	V	$I_E = -100\mu A, I_C = 0$		
Collector-Base Cutoff Current		_	_	-50	nA	$V_{CB} = -120V, I_{E} = 0$		
Collector-base Cuton Current	I _{CBO}	_	_	-50	μA	$V_{CB} = -120V$, $I_E = 0$, $T_A = +100$ °C		
Base-Emitter Cutoff Current	I _{EBO}	_	_	-50	nA	$V_{EB} = -5V, I_C = 0$		
ON CHARACTERISTICS (Note 9)								
	h _{FE}	50		_	_	$I_C = -1.0$ mA, $V_{CE} = -5.0$ V		
DC Current Gain		60	_	240		$I_C = -10$ mA, $V_{CE} = -5.0$ V		
		50		_		$I_C = -50 \text{mA}, V_{CE} = -5.0 \text{V}$		
Collector-Emitter Saturation Voltage	\/	_	_	-0.2	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$		
Conector-Emitter Saturation Voltage	V _{CE(sat)}			-0.5		$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$		
Base-Emitter Saturation Voltage	V	_	_	-1.0	V	I _C = -10mA, I _B = -1.0mA		
Base-Efficier Saturation Voltage	V _{BE(sat)}					$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$		
SMALL SIGNAL CHARACTERISTICS	SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C _{obo}	_	_	6.0	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$		
Small Signal Current Gain	h _{fe}	40	_	200	_	$I_C = -1mA$, $V_{CE} = -10V$, $f = 1.0MHz$		
Current Gain-Bandwidth Product	f_{T}	100	_	300	MHz	I _C = -10mA, V _{CE} = -10V, f = 100MHz		
Noise Figure	NF	_	_	8.0	dB	V_{CE} = -5.0V, I_{C} = -200 μ A, R_{S} = 10 Ω , f = 1.0kHz		

Notes:

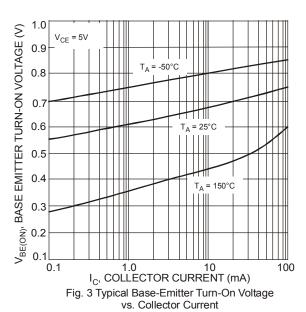
- 5. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted 25mm X 25mm 2oz copper.
- 7. Maximum combined dissipation.
- 8. Thermal resistance from junction to the top of package.
- 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







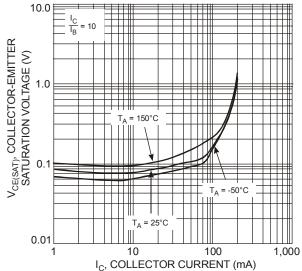


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

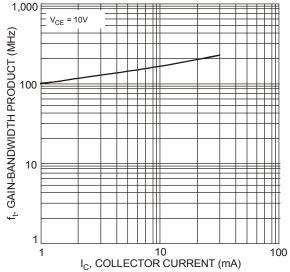
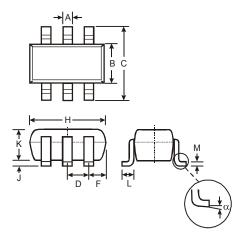


Fig. 4 Typical Gain-Bandwidth Product vs Collector Current



Package Outline Dimensions

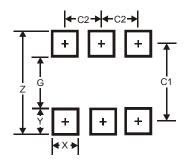
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT363						
Dim	Min Max Typ						
Α	0.10	0.30	0.25				
В	1.15	1.35	1.30				
C	2.00	2.20	2.10				
D	0.65 Typ						
F	0.40	0.45	0.425				
Н	1.80	2.20	2.15				
J	0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.22	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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